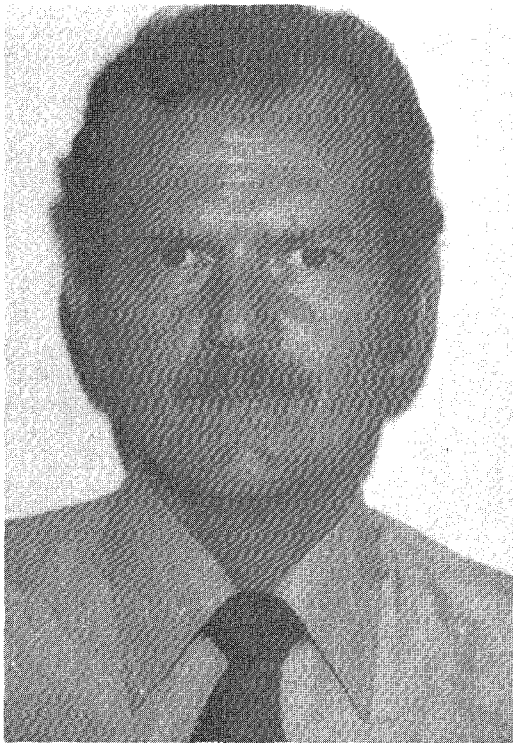


### 1979 MTT-S MICROWAVE APPLICATION AWARD

For the development of microwave silicon and GaAs microwave analog and digital integrated circuit.



Dale H. Claxton was born in Stapleton, Staten Island, New York, on June 11, 1943. He received the B.S. and M.S. degrees in electrical engineering from U.C.L.A. in 1972 and 1974, respectively. He joined TRW Defense and Space Systems Group in April 1973, and is currently a Section Head in the Microwave Technology Department of the Communications and Antennas Laboratory. Since joining TRW, he has been involved in the research and development of microwave devices, circuits and subsystems for high performance communications systems. Areas of past and current research include broadband low noise IMPATT, bipolar and FET VCOs, bipolar transistor analog integrated circuits, GaAs transferred electron logic devices and FETs, high speed digital and analog GaAs integrated circuits, and the systems applications of the above.

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